



# On the thermal stability of ultrafine-grained Al stabilized by *in-situ* amorphous Al<sub>2</sub>O<sub>3</sub> network



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## ABSTRACT

Bulk Al materials with average grain sizes of 0.47 and 2.4 μm, were fabricated by quasi-isostatic forging consolidation of two types of Al powders with average particle sizes of 1.3 and 8.9 μm, respectively. By utilizing the native amorphous Al<sub>2</sub>O<sub>3</sub> (am-Al<sub>2</sub>O<sub>3</sub>) film on the Al powders surfaces, a continuous, ~7 nm thick, am-Al<sub>2</sub>O<sub>3</sub> network was formed *in situ* in the Al specimens. Systematic investigation of the changes to the am-Al<sub>2</sub>O<sub>3</sub> network embedded in the Al matrix upon heating and annealing up to 600 °C was performed by transmission electron microscopy (TEM). At the same time, the stability of the Al grain structure was studied by transmission Kikuchi diffraction (TKD), electron back-scatter diffraction (EBSD), and TEM. The am-Al<sub>2</sub>O<sub>3</sub> network remained stable after annealing at 400 °C for 24 h. *In-situ* TEM studies revealed that at temperatures ≥ 450 °C, phase transformation of the am-Al<sub>2</sub>O<sub>3</sub> network to crystalline γ-Al<sub>2</sub>O<sub>3</sub> particles occurred. After annealing at 600 °C for 24 h the transformation was completed, whereby only nanometric γ-Al<sub>2</sub>O<sub>3</sub> particles with an average size of 28 nm resided on the high angle grain boundaries of Al. Due to the pinning effect of γ-Al<sub>2</sub>O<sub>3</sub>, the Al grain and subgrain structures remained unchanged during annealing up to 600 °C for 24 h. The effect of the am-Al<sub>2</sub>O<sub>3</sub> → γ-Al<sub>2</sub>O<sub>3</sub> transformation on the mechanical properties of ultrafine- and fine-grained Al is discussed from the standpoint of the underlying mechanisms.

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## 1. Introduction

Traditionally, Al-based components are fabricated either by casting or deformation and/or machining of wrought feedstock. Compared to traditional techniques, powder metallurgy (PM) offers various advantages, including: (i) microstructural refinement, increased solubility of alloying elements, and a homogenous microstructure, resulting in enhanced mechanical properties; (ii) the flexibility to produce metal matrix composites (MMCs) by incorporating strengthening phases with various matrix chemistries; and (iii) cost effective production of (near) net-shape complex parts. Typically, Al PM parts are fabricated from gas atomized feedstock powder material.

The exceptionally high thermodynamic stability of the Al<sub>2</sub>O<sub>3</sub> phase leads to the formation of a continuous protective Al<sub>2</sub>O<sub>3</sub> film covering all of the gas atomized Al powder surfaces, even under

high vacuum conditions [1]. Moreover, because of the high cooling rates that are typical of atomization, and the resulting fine powder sizes and structure, the native Al<sub>2</sub>O<sub>3</sub> films on the surface of as-atomized powders (especially those with finer size) are amorphous (am-Al<sub>2</sub>O<sub>3</sub>) [2–4], with a thickness of ~2–3 nm [2,4–7]. The amorphous state is preferred below the critical film thickness, because the higher bulk Gibbs free energy of am-Al<sub>2</sub>O<sub>3</sub> film, compared to crystalline γ-Al<sub>2</sub>O<sub>3</sub> film, is overcompensated for by the low value of the combined am-Al<sub>2</sub>O<sub>3</sub> surface and am-Al<sub>2</sub>O<sub>3</sub>/Al interfacial energies [8]. The am-Al<sub>2</sub>O<sub>3</sub> remains thermodynamically stable up to the critical thickness of ~5 nm [4,8] depending on the crystallographic orientation of the Al substrate and temperature [4,9]. Once this critical thickness is exceeded, am-Al<sub>2</sub>O<sub>3</sub> will transform to crystalline γ-Al<sub>2</sub>O<sub>3</sub> (or transitional γ-Al<sub>2</sub>O<sub>3</sub>) in the range 450–550 °C [4,10]. The γ-Al<sub>2</sub>O<sub>3</sub> crystals grow epitaxially in respect to an Al substrate on am-Al<sub>2</sub>O<sub>3</sub>/Al interface [11] and later they develop preferentially along the grain boundaries [12]. The growth of γ-Al<sub>2</sub>O<sub>3</sub> films is limited by the rate of inward oxygen diffusion through the films. The γ-Al<sub>2</sub>O<sub>3</sub> on the surface of loose powder remains thermodynamically stable during thermal exposures to temperatures normally associated with Al PM

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processing, i.e., up to the melting point of Al ( $T_m=660\text{ }^{\circ}\text{C}$ ) [4]. Consequently, any  $\alpha\text{-Al}_2\text{O}_3$  or  $\gamma\text{-Al}_2\text{O}_3$  phases present on Al particle surfaces behave as a dispersed second phase during powder processing and consolidation. This finding is universal and applies for a wide range of PM processing/consolidation techniques including: ball milling [13,14], hot working (e.g., forging, extrusion) [15,16], sintering (e.g., conventional, spark plasma sintering (SPS)) [17,18], hot isostatic pressing (HIP) [15,19] and severe plastic deformation [20]. Typically, the volume fraction of *in-situ*  $\text{Al}_2\text{O}_3$  phase in PM parts fabricated from gas atomized powders varies between  $\sim 0.1$  and  $\sim 3\text{ vol}\%$  [7]. Depending on the processing and parameters used during consolidation, the dispersed  $\text{Al}_2\text{O}_3$  phase either persists in the form of an amorphous, nanometric, continuous network or discrete platelets [3]. Otherwise, it crystallizes into nanometric  $\gamma\text{-Al}_2\text{O}_3$  particles [15]. Similar to the crystallization of the native  $\alpha\text{-Al}_2\text{O}_3$  films on as-atomized powders under an oxidizing environment, the nanometric  $\alpha\text{-Al}_2\text{O}_3$  dispersed phase (network or platelets) in Al matrix remains thermodynamically stable upon annealing to  $\sim 450\text{ }^{\circ}\text{C}$ , where it transforms into nanometric  $\gamma\text{-Al}_2\text{O}_3$  particles [3,19]. However, the transformation mechanism, the nature of  $\text{Al}_2\text{O}_3$  phases (specifically in terms of size, crystallinity and distribution) and their thermal stability in an absence of direct diffusion of gaseous oxygen, all remain open questions.

The presence of the *in-situ*  $\text{Al}_2\text{O}_3$  dispersed phase, especially for those PM parts fabricated from coarse powders, is often neglected despite the findings that the *in-situ*  $\text{Al}_2\text{O}_3$  dispersoids can restrict grain growth up to high homologous temperatures [7,13]. Moreover, the  $\text{Al}_2\text{O}_3$  phase may contribute to strengthening, stiffening and creep resistance of the Al matrix in a broad temperature range [3,7,21]. Initial mechanical behavior data indicate that  $\alpha\text{-Al}_2\text{O}_3$  is more efficient in strengthening and stiffening of the Al matrix in comparison to  $\gamma\text{-Al}_2\text{O}_3$  [3]. In addition, the materials with  $\alpha\text{-Al}_2\text{O}_3$  phase, either in the form of network or platelets, show superior creep performance [15,21,22]. However, fundamental information related to the strengthening and grain pinning effects of  $\alpha\text{-Al}_2\text{O}_3$  and  $\gamma\text{-Al}_2\text{O}_3$  phases in Al PM structures has yet to be established. Motivated by these factors, the objective of the present work is threefold and it aims to investigate:

- the changes of  $\alpha\text{-Al}_2\text{O}_3$  phase dispersed in PM Al upon heating;
- the effect of the  $\alpha\text{-Al}_2\text{O}_3 \rightarrow \gamma\text{-Al}_2\text{O}_3$  transformation on the mechanical properties of PM Al; and
- the stabilizing effect of  $\alpha\text{-Al}_2\text{O}_3$  and  $\gamma\text{-Al}_2\text{O}_3$  phases on Al grain structure.

For this purpose, bulk Al MMCs reinforced and stabilized with a nanometric  $\alpha\text{-Al}_2\text{O}_3$  network with the commercial designation HITEMAL<sup>®</sup> (high temperature aluminum), were fabricated *in situ* by quasi-isostatic forging (QIF) compaction of fine gas-atomized commercial purity (CP) Al powders with particle sizes of  $1\text{--}10\text{ }\mu\text{m}$  [3]. In these composites, a nearly continuous  $\alpha\text{-Al}_2\text{O}_3$  network, with a relatively large volume fraction (up to  $2.7\text{ vol}\%$ ), forms during QIF as result of subtly sheared Al powders with only limited fracturing of native  $\alpha\text{-Al}_2\text{O}_3$  films. The grain structure of QIF HITEMAL is characterized by a mixture of high and low angle grain boundaries (HAGBs, LAGBs), where  $\alpha\text{-Al}_2\text{O}_3$  resides at HAGBs,

and LAGBs are free of  $\text{Al}_2\text{O}_3$  [3]. Ultrafine-grained (UFG) HITEMAL virtually free of LAGBs and fine-grained (FG) HITEMAL with developed subgrain structures were fabricated from two types of fine CP Al powders of different particle sizes in order to elucidate the stabilizing effect of  $\text{Al}_2\text{O}_3$  on LAGBs. At the same time, the effect of different grain size on susceptibility to grain coarsening was studied. Moreover, the effect of the  $\alpha\text{-Al}_2\text{O}_3 \rightarrow \gamma\text{-Al}_2\text{O}_3$  transformation on UFG and FG materials with distinctively different deformation behavior was studied.

## 2. Experimental

Two different types of commercially available nitrogen atomized Al powders ( $\text{Al} \geq 99.8\text{ wt}\%$ ) with median particle sizes ( $d_{50}$ ) of  $1.4$  and  $8.9\text{ }\mu\text{m}$  were used for this study. The specific powder surface area of the powders, determined by physical adsorption with multipoint analysis using nitrogen gas according to the Brunauer-Emmett-Teller (BET) principle, was  $3.1$  and  $0.9\text{ m}^2\text{ g}^{-1}$ , respectively. The loose powders were pressed by cold isostatic pressing (CIP) at  $20\text{ MPa}$ . Blanks  $35\text{ mm}$  in diameter and  $50\text{ mm}$  in length were machined from CIPed green compacts. The blanks were subjected to  $5\text{ Pa}$  vacuum degassing (VD) performed at  $425\text{ }^{\circ}\text{C}$  for  $12\text{ h}$ . VDED blanks were evacuated for  $12\text{ h}$  in a vacuum chamber prior to vacuum hot pressing (VHP) performed at  $425\text{ }^{\circ}\text{C}$  and  $370\text{ MPa}$ . VHPed blanks were consolidated by QIF with a limited amount of shear deformation. QIF was carried out at  $420\text{ }^{\circ}\text{C}$  and impact energy of  $14\text{ kJ}$  using a screw press FICEP PVX160, and a semi closed forging die. The materials forged from Al powders of  $d_{50}=1.3$  and  $8.9\text{ }\mu\text{m}$  were labeled as A and B, respectively. To eliminate the work hardening effects induced during processing, as-forged materials were annealed at  $400\text{ }^{\circ}\text{C}$  for  $24\text{ h}$  (hereafter referred to as the “as-processed” material). In order to execute the  $\alpha\text{-Al}_2\text{O}_3 \rightarrow \gamma\text{-Al}_2\text{O}_3$  transformation, as-forged materials were annealed in an Ar atmosphere at  $500$  and  $600\text{ }^{\circ}\text{C}$  for  $24\text{ h}$  prior to characterization and testing. The designation for all samples and annealing conditions is summarized in Table 1.

The materials' densities were measured by using the Archimedes' principle. Samples were characterized by using a JEOL 2500SE TEM equipped with an *in-situ* hot stage holder and a Phillips XL-30 scanning electron microscope (SEM) equipped with an Oxford NordlysNano electron back-scatter diffraction (EBSD) detector. The heating rate during *in-situ* TEM was set to be  $5\text{ }^{\circ}\text{C min}^{-1}$  with  $30\text{ min}$  dwells at  $400$ ,  $450$ ,  $500$ ,  $550$  and  $600\text{ }^{\circ}\text{C}$ , respectively. In order to maintain uniform thermal exposure conditions, the same heating sequence was applied for all *in-situ* TEM. Energy dispersive X-ray spectrometry (EDS), EBSD and transmission Kikuchi diffraction (TKD) [23,24] were used to assist in the analysis. For FG B materials the average grain size and the misorientation of neighboring grains were determined by SEM equipped with EBSD using  $2 \times 2 \times 2\text{ mm}^3$  samples. In order to improve the index rate, the average grain size and the misorientation of neighboring grains of UFG A materials were determined by SEM equipped with EBSD using thin foils (i.e., by TKD). Thin foils for TEM and TKD were prepared by electric discharge machining (EDM), mechanical grinding and dimpling followed by the final thinning carried out by Ar ion milling at  $4\text{ kV}$  and cooled by liquid nitrogen. The specimens for EBSD analyses

**Table 1**  
The designation of as-forged and annealed materials.

Material	$d_{50}\text{ (}\mu\text{m)}$	BET ( $\text{m}^2\text{ g}^{-1}$ )	As-forged	Annealed at $400\text{ }^{\circ}\text{C}$ for $24\text{ h}$ (as-processed)	Annealed at $500\text{ }^{\circ}\text{C}$ for $24\text{ h}$	Annealed at $600\text{ }^{\circ}\text{C}$ for $24\text{ h}$
A	1.4	3.1	A0	A400	A500	A600
B	8.9	0.9	B0	B400	B500	B600

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